# MA3X740 (MA740)

## Silicon epitaxial planar type

For super high speed switching For small current rectification

## ■ Features

- Two MA3X721 (MA721) is contained in one package (series connection)
- Forward current (Average)  $I_{F(AV)} = 200 \text{ mA}$  (per single diode) rectification is possible

## ■ Absolute Maximum Ratings $T_a = 25$ °C

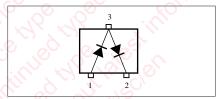
Parameter		Symbol	Rating	Unit	
Reverse voltage		$V_R$	30	V	
Repetitive peak reverse voltage		V <sub>RRM</sub>	30	V	
Forward current	Single	I <sub>F(AV)</sub>	200	mA	
(Average)	Series		130		
Peak forward	Single	$I_{FM}$	300	mA	
current	Series		220	110	
Non-repetitive peak	Single	I <sub>FSM</sub>	1.0	A	
forward surge current *	Series		0.7	65 X	
Junction temperature		T <sub>j</sub>	150	°C	
Storage temperature		$T_{stg}$	-55 to +150	°C	

Note) \*: The peak-to-peak value in one cycle of 50 Hz sine wave (non-repetitive)

# Unit: mm 0.40<sup>+0.10</sup> 0.16<sup>+0.10</sup> 0.16<sup>+0.10</sup> 1. Anode 1 2: Cathode 2 3: Cathode 1 Anode 2 Mini3-G1 Package

Marking Symbol: M3C

## Internal Connection

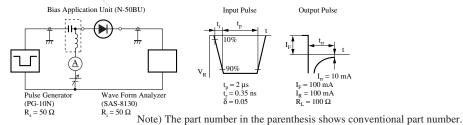


## ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

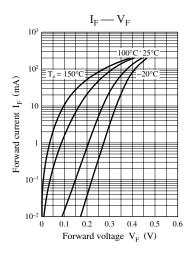
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	$V_{\mathrm{F}}$	$I_F = 200 \text{ mA}$	)		0.55	V
Reverse current	$I_R$	$V_R = 30 \text{ V}$			50	μΑ
Terminal capacitance	C <sub>t</sub>	$V_R = 0 V, f = 1 MHz$		30		pF
Reverse recovery time *	t <sub>rr</sub>	$I_F = I_R = 100 \text{ mA}$		3.0		ns
		$I_{rr} = 10 \text{ mA}, R_L = 100 \Omega$				

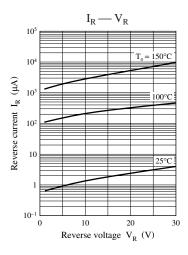
- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
  - 2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
  - 3. Absolute frequency of input and output is 1 GHz.

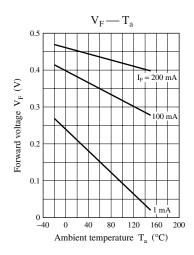
4. \*: t<sub>rr</sub> measurement circuit

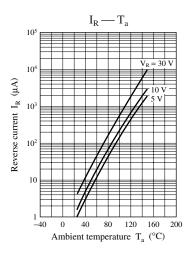


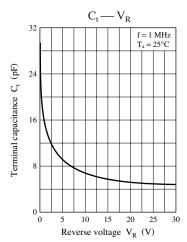
## **Panasonic**











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